

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:)	
	Toshiki Makimoto, et al.)	
)	
Serial No.:	10/516,380)	Art Unit
)	2811
Filed:	November 30, 2004)	
)	
Confirmation No.:	2860)	
)	
For:	P-TYPE NITRIDE SEMICONDUCTOR)	
	STRUCTURE AND BIPOLAR TRANSISTOR)	
)	
Examiner:	Toshiki Makimoto)	

AUTHORIZATION TO CHARGE DEPOSIT ACCOUNT

Commissioner for Patents
PO Box 1450
Alexandria, Virginia 22313-1450

Sir:

The Commissioner is hereby authorized to charge payment of the following fees associated with this communication or credit any overpayment to Deposit Account No. 23-3178.

X Any additional filing fees required under 37 CFR § 1.16.

X Any patent application processing fees under 37 CFR § 1.17.

Dated this 29th day of November 2006.

Respectfully submitted,

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